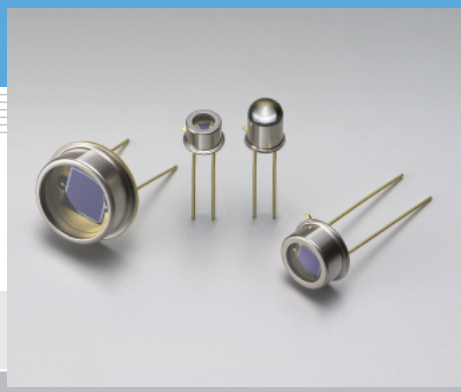


Si photodiode S2386 series

For visible to IR, general-purpose photometry



Features

- High sensitivity
- Low dark current
- High reliability
- High linearity

Applications

- Analytical equipment
- Optical measurement equipment

■ General ratings / Absolute maximum ratings

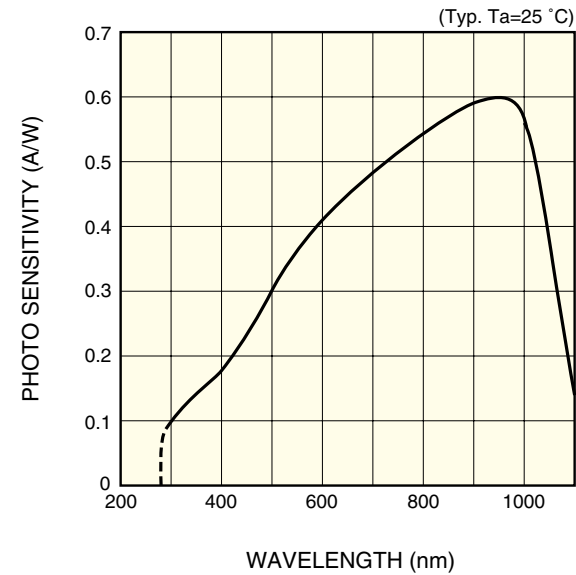
Type No.	Dimensional outline/ Window material *	Package (mm)	Active area size (mm)	Effective active area (mm ²)	Absolute maximum ratings		
					Reverse voltage V _R Max. (V)	Operating temperature T _{opr} (°C)	Storage temperature T _{stg} (°C)
S2386-18K	①/K	TO-18	1.1 × 1.1	1.2	30	-40 to +100	-55 to +125
S2386-18L	②/L						
S2386-5K	③/K	TO-5	2.4 × 2.4	5.7			
S2386-44K			3.6 × 3.6	13			
S2386-45K			3.9 × 4.6	17.9			
S2386-8K	④/L	TO-8	5.8 × 5.8	33			

■ Electrical and optical characteristics (Typ. T_a=25 °C, unless otherwise noted)

Type No.	Spectral response range λ (nm)	Peak sensitivity wavelength λ _p (nm)	Photo sensitivity S (A/W)				Short circuit current I _{sc} 100 lx		Dark current I _D V _R =10 mV Max. (pA)	Temp. coefficient of I _D T _{CID} (times/°C)	Rise time t _r V _R =0 V R _L =1 kΩ (μs)	Terminal capacitance C _t V _R =0 V f=10 kHz (pF)	Shunt resistance R _{sh} V _R =10 mV		NEP (W/Hz ^{1/2})
			λ _p	GaP LED 560 nm	He-Ne laser 633 nm	GaAs LED 930 nm	Min. (μA)	Typ. (μA)					Min. (GΩ)	Typ. (GΩ)	
S2386-18K	320 to 1100	960	0.6	0.38	0.43	0.59	1	1.3	2	1.12	0.4	140	5	100	6.8 × 10 ⁻¹⁶
S2386-18L							4	5.7					25		
S2386-5K							4.4	6.0						5	
S2386-44K							9.6	12						20	
S2386-45K							12	17						30	
S2386-8K							26	33						50	

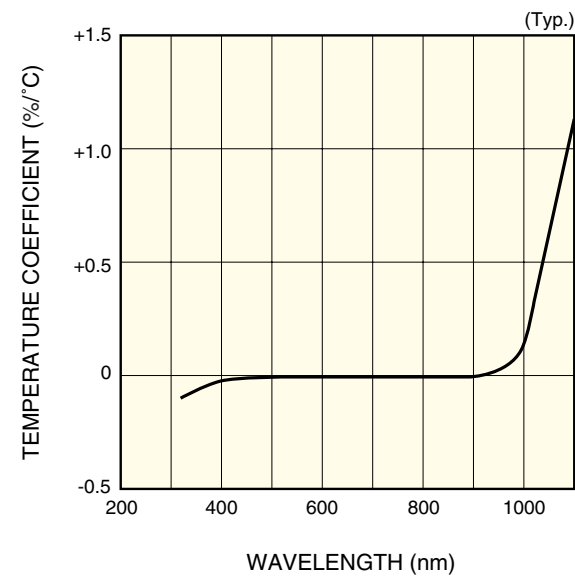
* Window material K: borosilicate glass, L: lens type borosilicate glass

■ Spectral response



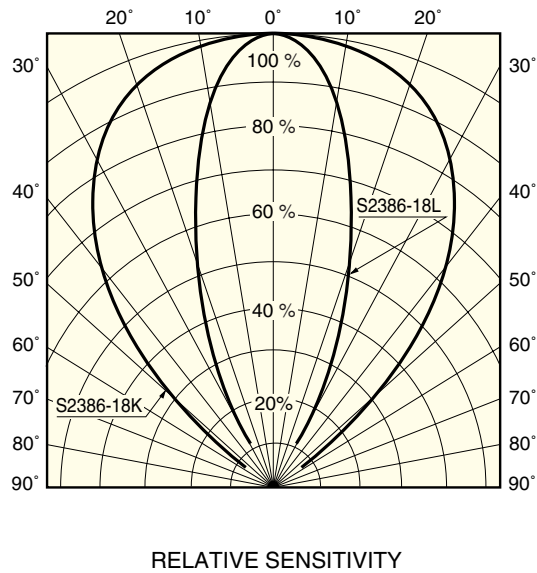
KSPDB0110EA

■ Photo sensitivity temperature characteristic



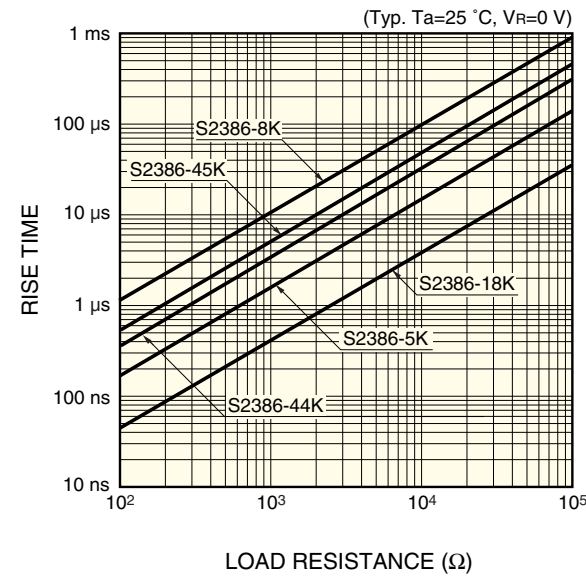
KSPDB0058EB

■ Directivity



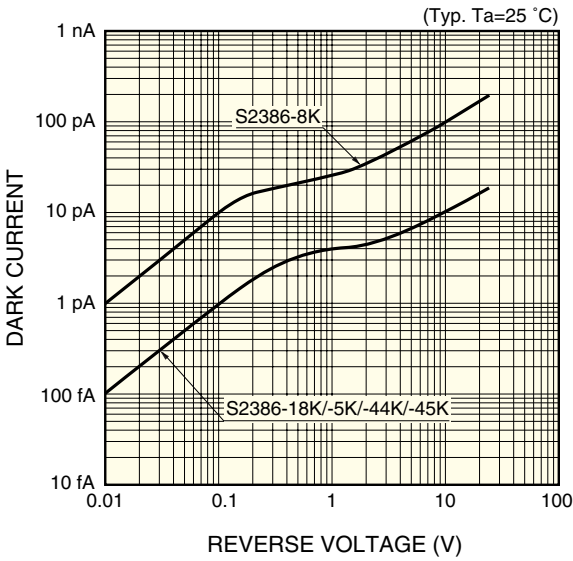
KSPDB0111EA

■ Rise time vs. load resistance



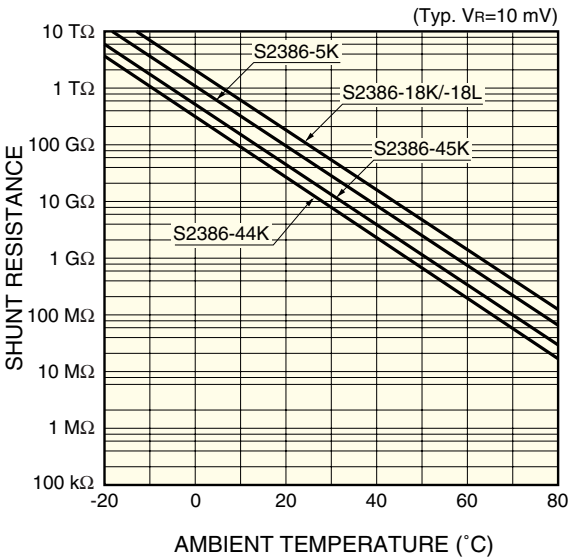
KSPDB0112EA

■ Dark current vs. reverse voltage



KSPDB0113EA

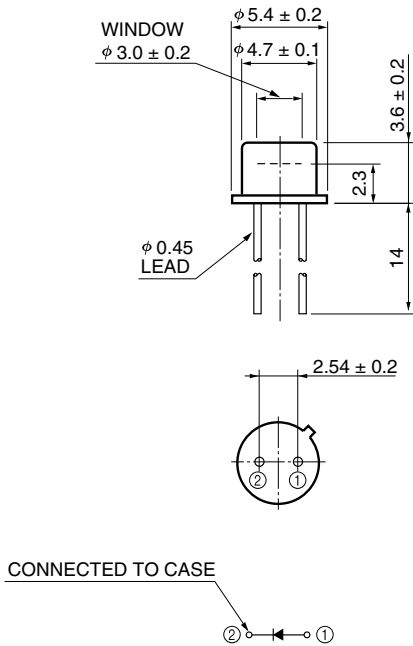
■ Shunt resistance vs. ambient temperature



KSPDB0114EA

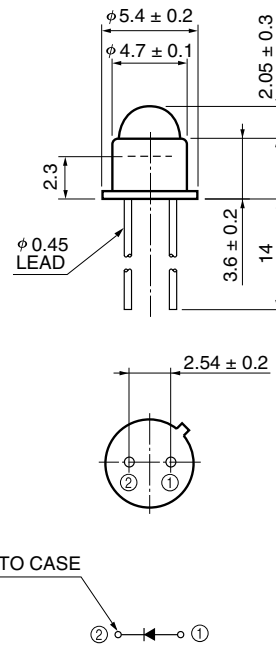
■ Dimensional outlines (unit: mm)

① S2386-18K



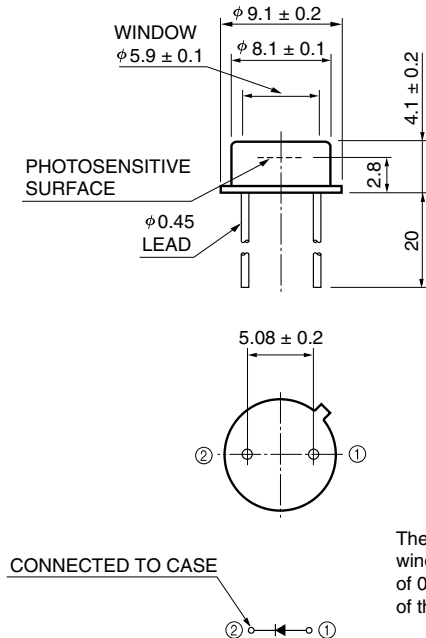
KSPDA0102EB

② S2386-18L



KSPDA0048EB

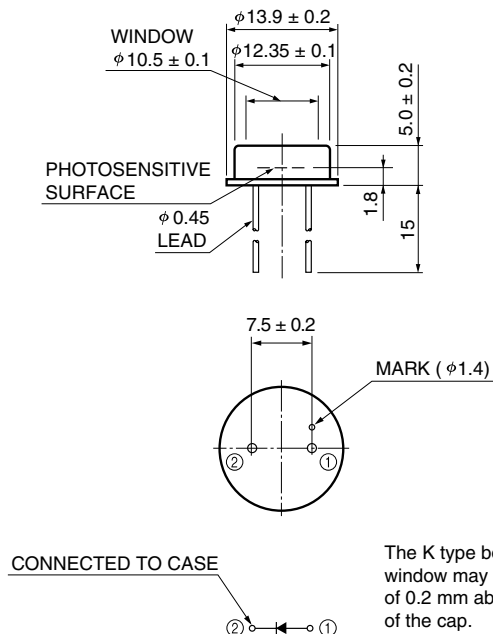
③ S2386-5K/-44K/-45K



The K type borosilicate glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0103EA

④ S2386-8K



The K type borosilicate glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0104EA

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Cat. No. KSPD1035E02
Oct. 2002 DN